UNITED STATES PATENT AND TRADEMARK OFFICE

BIB DATA SHEET

CONFIRMATION NO. 3566

SERIAL NUMBER	FILING or 371(c) DATE	CLASS	GROUP ART UNIT	ATTORNEY DOCKET NO.
10/575,785	04/14/2006 **RULE**	257	2813	03680036AA

APPLICANTS
    Kensuke Takahashi, Tokyo, JAPAN;
    Kenzo Manabe, Tokyo, JAPAN;
    Nobuyuki Ikarashi, Tokyo, JAPAN;
    Toru Tatsumi, Tokyo, JAPAN;

** CONTINUING DATA *************************
    This application is a 371 of PCT/JP05/11331 06/21/2005

** FOREIGN APPLICATIONS *************************
    JAPAN 2004-184758 06/23/2004

** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **
    03/13/2007

Foreign Priority claimed	☑Yes ☐No		STATE OR COUNTRY	SHEETS DRAWINGS	TOTAL CLAIMS	INDEPENDENT CLAIMS
35 USC 119(a-d) conditions met	☑Yes ☐No	☐ Met after Allowance	JAPAN	10	36	13
Verified and Acknowledged	/STEPHEN W SMOOT/ Examiner's Signature	Initials				

ADDRESS

    WHITHAM, CURTIS & CHRISTOFFERSON & COOK, P.C.
    11491 SUNSET HILLS ROAD
    SUITE 340
    RESTON, VA 20190
    UNITED STATES

TITLE

    Semiconductor device with silicide-containing gate electrode and method of fabricating the same

FILING FEE RECEIVED 5160	FEES: Authority has been given in Paper No._____ to charge/credit DEPOSIT ACCOUNT No._____ for following:	☐ All Fees
		☐ 1.16 Fees (Filing)
		☐ 1.17 Fees (Processing Ext. of time)
		☐ 1.18 Fees (Issue)
		☐ Other _____
		☐ Credit